

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3842	mram and "magnetic random access memory"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:52
L2	8189	mram or "magnetic random access memory"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:52
L3	1215	l1 and pin\$3 and parallel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:54
L4	632	l3 and "free layer"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:55
L5	614	l4 and (resistance or resistive)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:56
L6	376	l5 and (("bit line" or bitline) same field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 10:12
L7	23	l5 and (("bit line" or bitline) same field same vertical)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:57
S1	4	((("5732026") or ("6236590")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2006/01/30 16:46
S2	9088	magnetoresistance	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/01/30 17:31
S3	317	S2 and overlap and perpendicular	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/01/30 17:31

S4	1	S3 and (overlap near "bit line")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/01/30 17:33
S5	31	S3 and (overlap same "bit line")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2006/02/01 07:51